

Theoretical Analysis of a New Technique for Inertial Rotation Sensing Using a Semiconductor Ring Laser

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Abstract—We introduce a new technique for the measurement of inertial rotations using a semiconductor ring laser. Inertial rotation introduces a frequency deviation of the optical frequency of the two counterpropagating waves in the laser cavity, whereas mode coupling causes frequency attraction (frequency pushing) and finally locking at low rotation rates, washing out the small Sagnac frequency difference to be measured. Here we propose to measure inertial rotation within the so-called *locking band* using the phase/amplitude dependence on detuning found for the oscillating modes under the gain line. The dephasing accumulated by the two counterpropagating waves unbalances the fields' amplitudes within the locking region. We analytically derive the responsivity function quantifying the two-mode power unbalance versus rotation rate, by means of a two-mode rate equations model. Noise performance of a possible rotations sensor are also discussed by calculating the noise equivalent rotation rate.

Index Terms—Laser dynamics, metrological applications, ring lasers, semiconductor lasers.

I. INTRODUCTION

SEMICONDUCTOR ring lasers (SRLs) [1] raised interest because their monolithic integration is easily achievable [2]. SRLs are used in numerous applications like wavelength filtering, unidirectional travelling-wave operation [3], multiplexing/demultiplexing applications, and data storage-gating as optical bistables [4]–[6]. One interesting potential application of an SRL is a semiconductor ring laser gyroscope (S-RLG) [7], [8], which could represent a compact, simple, and low-cost optical device for inertial rotation sensing.

The idea of using a ring interferometer as a rotation rate sensor was introduced by Sagnac [9], and became a technical reality after the assessment of a reliable laser technology. Optical gyroscopes are currently used in satellites, aircrafts, and remote-control devices. RLGs are based on the measurement of the detuning induced by rotation onto the optical frequency of the two counterpropagating modes in a ring laser. However, any source of intracavity backscattering couples and can lock the counterpropagating waves [10]–[12], representing a major source of error in practical devices [13].

The advantages of an S-RLG are monolithic integration, potential low cost, and small size. However, integrated S-RLGs

show a wide locking band of the order of 10–100 MHz [14] hindering the Sagnac effect for practical rotation rates.

In this letter, we theoretically show that an SRL can be used to measure inertial rotation within the so-called locking band, i.e., without the need to unlock the two counterpropagating waves. Indeed, the dephasing accumulated by the two counterpropagating waves due to rotation within the locking region is coupled to the field amplitudes via conservative backscattering. This in turn unbalances the field amplitudes by a quantity proportional to the rotation angular velocity. We provide analytical expression for the *responsivity* that would characterize a possible rotation sensor. Moreover, we consider the quantum fluctuations [8] of the fields to calculate the noise equivalent rotation rate (NER), obtaining 10^{-3} Hz assuming 10 mW of output power. The obtained NER is higher than what is typically displayed by He–Ne RLG; however, the limited cost and size of an S-RLG could make it appealing for rotation sensing applications. Also, this technique can be exported to other ring lasers than SRLs, if an intracavity mechanism of conservative backscattering is provided.

The theoretical analysis is based on a set of dimensionless dynamical equations [14], [15] for the two (slowly varying) complex amplitudes of the counterpropagating fields E_+ and E_- modified to account for inertial rotation effects [10], [16] and a Bloch equation for the carrier density N . The equations read

$$\begin{aligned}\dot{E}_{\pm}(t) &= \mathcal{G}_{\pm} \left(N(t), |E_{\pm}(t)|^2 \right) E_{\pm}(t) - \eta E_{\mp}(t) \pm i\Delta E_{\pm}(t) \\ \dot{N}(t) &= \gamma \mathcal{F} \left(N(t), |E_{\pm}(t)|^2 \right)\end{aligned}\quad (1)$$

where

$$\begin{aligned}\mathcal{G}_{\pm} \left(N(t), |E_{\pm}(t)|^2 \right) &= \frac{1}{2}(1 + i\alpha) \{N(t)\sigma_{\pm} - 1\} \\ \mathcal{F} \left(N(t), |E_{\pm}(t)|^2 \right) &= \mu - N(t) - N(t)\sigma_{+} |E_{+}(t)|^2 \\ &\quad - N(t)\sigma_{-} |E_{-}(t)|^2 \\ \sigma_{\pm} &= 1 - s |E_{\pm}(t)|^2 - c |E_{\mp}(t)|^2.\end{aligned}$$

The parameter α accounts for phase-amplitude coupling and the self and cross saturation coefficients are given by s and c , respectively; $\eta = k_d + ik_c$ is the complex backscattering coefficient where the parameters k_d and k_c represent the dissipative and conservative components of the backscattering, respectively, and 2Δ is the rotation-induced frequency difference. The carrier density N obeys the Bloch equation for semiconductor lasers, where μ is the dimensionless pump ($\mu = 1$ at laser threshold). In the set (1), the dimensionless time is rescaled by the photon lifetime τ_p . The parameter γ is the ratio of the carrier lifetime τ_s over τ_p .

Consistently with the standard theory [16], the emission frequency of the two modes (referred to a common optical carrier

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set to zero) is shifted by the inertial rotation of a dimensionless (because of time rescaling) amount equal to 2Δ , when the rotation vector is orthogonal to the cavity plane

$$\Delta = \frac{2\pi R\tau_p}{\lambda} \Omega_{\text{rot}} \quad (2)$$

where R is the ring radius, λ is the laser wavelength, and Ω_{rot} is the dimensional rotation angular velocity. First we analyze the SRL at rest ($\Delta = 0$). We look for a solution of the following form for the set (1):

$$E_{\pm}(t) = Q_{\pm} e^{i(\omega t \pm \psi/2)}, \quad N(t) = \bar{N}. \quad (3)$$

By substitution of (3) in the set (1) with $\Delta = 0$, we find [15] symmetric steady-state solutions for the carrier density and the amplitudes of the fields

$$\bar{N} = \frac{\mu}{1 + 2Q^2 - 2(c+s)Q^4} \quad (4)$$

$$Q_{\pm}^2 = Q^2 = \frac{\bar{N} - 1 + k_d}{(c+s)\bar{N}}. \quad (5)$$

There are two possible cases characterized by two stationary values of the relative phase, the *in phase* case, $\psi = 0$, with corresponding oscillation frequency

$$\omega_{in} = \alpha k_d - k_c \quad (6)$$

and the *out of phase* case, $\psi = \pi$, with corresponding frequency

$$\omega_{out} = -\alpha k_d + k_c. \quad (7)$$

Depending on the sign of the backscattering parameters, one of the solutions is stable and the other unstable; if $k_d > 0$ the *out of phase* case is stable, and the *in phase* case is stable for $k_d < 0$. The set (1) presents other solutions (i.e., alternate oscillations, bistability); in this work, we focus on the effect of a Sagnac detuning on the symmetric solution. From now on, we focus on the *in phase* case without losing generality. If Δ is small, the stationary solution deviate from the solution at rest (4)–(6). Assuming a amplitude deviation of the form

$$Q_{\pm} = Q \pm \delta \quad (8)$$

and a small deviation θ of the relative phase ψ . By substituting the deviations with (3) in the set (1), at first order in δ and θ , separating the real and the imaginary part, we obtain a set of two linear coupled equations for the perturbations δ and θ , i.e.,

$$\begin{aligned} \Delta Q + k_d \theta Q + 2k_c \delta - \alpha Q^2 \delta \bar{N} (s - c) &= 0 \\ 2k_d \delta - k_c \theta Q - \bar{N} Q^2 \delta (s - c) &= 0. \end{aligned} \quad (9)$$

We define χ as the difference between the fields' intensities divided by the total intensity; using (3) with (4)–(8), we obtain

$$\chi = \frac{|E_-|^2 - |E_+|^2}{|E_+|^2 + |E_-|^2} = \frac{2}{Q} \delta = \mathcal{R} \Omega_{\text{rot}} \quad (10)$$

where \mathcal{R} is the responsivity of the system to the dimensional inertial rotation Ω_{rot} ; by solving (9) and using (10), we find the analytical expression for the dimensional [Hz^{-1}] responsivity function

$$\mathcal{R} = \frac{4\pi k_c R \tau_p}{\lambda (2k_d^2 + 2k_c^2 - (k_d + \alpha k_c) Q^2 \bar{N} (s - c))}. \quad (11)$$

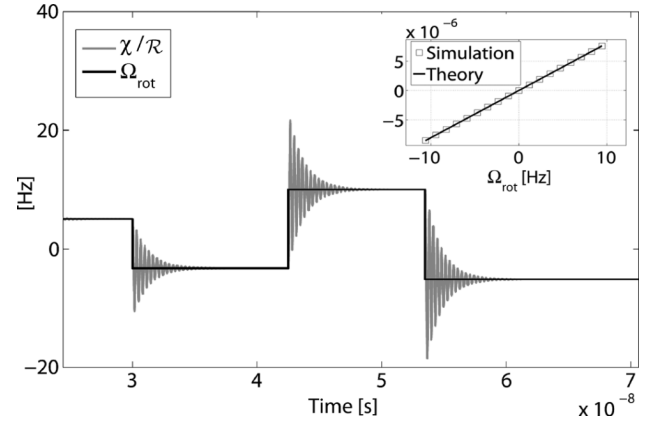


Fig. 1. Numerical simulations of the response of the SRL to a rotation depending on time. Inset: System response χ versus inertial rotation Ω_{rot} . The slope is the responsivity \mathcal{R} . The ring radius is $R = 600 \mu\text{m}$ and the pump is $\mu = 1.2$, $\alpha = 3.5$, $s = 0.005$, $c = 0.01$, $k_d = -3.27 \cdot 10^{-4}$, $k_c = 4.4 \cdot 10^{-3}$, and $\tau_p = 1$ ps. The parameter set is taken according to experimental fitting [15].

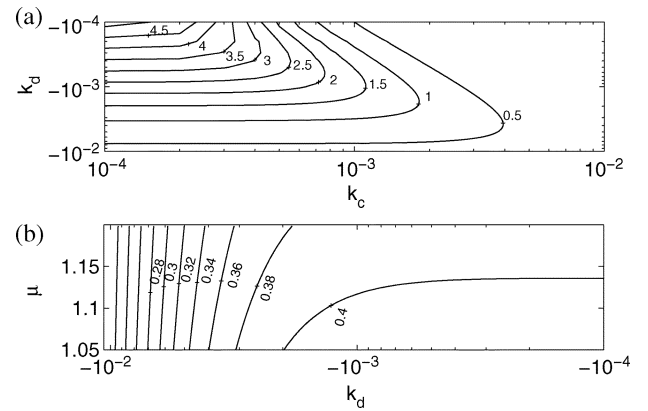


Fig. 2. (a) Responsivity ($\times 10^{-5}$) contour plot versus backscattering coefficients, $\mu = 1.2$; (b) responsivity ($\times 10^{-5}$) contour plot versus backscattering coefficient k_d and pump current, $k_c = 10^{-2}$. $\alpha = 3.5$, $s = 0.005$, $c = 0.01$, $\tau_p = 1$ ps, $R = 600 \mu\text{m}$, and $\lambda = 890$ nm.

The responsivity \mathcal{R} quantifies how the rotation unbalances the counterpropagating fields' intensities. In Fig. 1 (inset), χ is plotted versus the inertial rotation Ω_{rot} using the analytical expression (10), and compared to numerical simulations. Fig. 1 (inset) shows that our analytical approximations are well met and how rotation can be resolved without sign ambiguity.

Fig. 2(a) shows the responsivity behavior versus the real and imaginary part of the backscattering coefficient. Fig. 2(b) shows responsivity versus backscattering dissipative coefficient k_d and pump current μ . As a general trend, the responsivity decreases for increasing values for the dissipative backscattering coefficient and decreasing values for the conservative backscattering coefficient. Physically, the dissipative backscattering stabilizes the locking by damping the perturbations of the phase difference between the two modes. On the other side, conservative backscattering enhances the relative phase dynamics, thus making the system more sensitive to sources of dephasing like the Sagnac effect. Indeed (11) shows that the responsivity vanishes if $k_c = 0$. This is so because the relative dephasing accumulated by the two fields is coupled to the field amplitudes via conservative backscattering when Ω_{rot} is within the locking band. This effect is different from the amplitude

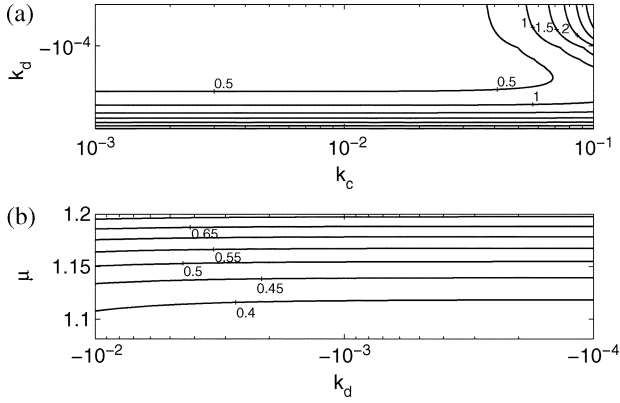


Fig. 3. (a) Ω_{NER} ($\times 10^{-2}$) contour plot versus backscattering coefficients, $\mu = 1.2$; (b) Ω_{NER} ($\times 10^{-2}$) contour plot versus backscattering coefficient k_d and pump current μ , $k_c = 10^{-2}$. $\alpha = 3.5$, $s = 0.005$, $c = 0.01$, $\tau_p = 1$ ps, $R = 600$ μm , $\lambda = 890$ nm, $B = 10$ Hz, and $P = 10$ mW.

modulation reported in [17], because in our case the two fields unbalance their continuous-wave component.

To characterize the response of the device to a rotation variation, we simulate the equation set (1) with a time-dependent rotation. The results are shown in Fig. 1; the response time of the device is a few nanoseconds for our parameter's choice.

Noise characteristics are also important to characterize the possible implementation of this technique in real gyroscopes. Considering the quantum fluctuations [8] for the optical power in each direction $P_{\pm} = |E_{\pm}|^2$

$$\langle \delta P_{\pm}^2 \rangle = \frac{2hcBP_{\pm}}{\lambda} \quad (12)$$

where B is the instrument bandwidth, c is the speed of light, and h is Planck's constant. Using (12) with (10), assuming $P_+ = P_- = P$ by straightforward calculation, we obtain the standard deviation of χ , assuming $\langle \delta P_{\pm}^2 \rangle^{1/2} \ll P$

$$\sigma_{\chi} = \langle \delta \chi^2 \rangle^{1/2} \simeq \sqrt{\frac{hBc}{\lambda P}} = \mathcal{R}\Omega_{\text{NER}} \quad (13)$$

that permits to calculate the noise equivalent rotation Ω_{NER} . Fig. 3(a) shows Ω_{NER} versus backscattering coefficients. The order of Ω_{NER} is $\sim 10^{-3}$ Hz for a wide range of parameter values for backscattering coefficients. Ω_{NER} grows with k_c and decreases with k_d . This is so because the conservative backscattering increases the phase-noise [18], whereas the dissipative backscattering dumps phase fluctuations. Fig. 3(b) shows how Ω_{NER} grows with the pump current.

II. CONCLUSION

We have introduced a simple theory for a new technique to measure inertial rotation using an SRL. We have derived an analytical expression for the responsivity function of a possible rotation sensor using a well-established two-mode rate equation model. We have investigated the effect of the backscattering coefficients and the pump current on the responsivity function, and the dynamic response of the device when a time-dependent

rotation rate is applied. We have considered quantum fluctuations in order to calculate the NER. Our conclusion is that the proposal of using an SRL as a rotation sensor is viable, as it is not necessarily limited by locking effects; the responsivity and noise performance are quite interesting compared to commercial laser gyroscope, taking into account the cost and size benefits of semiconductor laser technology. Moreover, this technique can be exported to any ring-laser gyroscope, providing an intracavity mechanism of conservative backscattering.

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